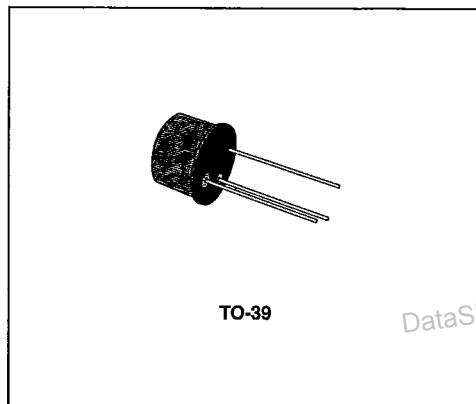
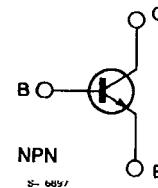
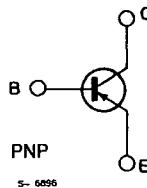


**S G S-THOMSON**
**AUDIO OUTPUT AMPLIFIER**
**DESCRIPTION**

The BC139 is a silicon planar epitaxial PNP transistor in a TO-39 metal case. It is particularly designed for use in audio output and driver stages. The complementary NPN type is the BC119.


**INTERNAL SCHEMATIC DIAGRAM**

DataSheet4U.com


**ABSOLUTE MAXIMUM RATINGS**

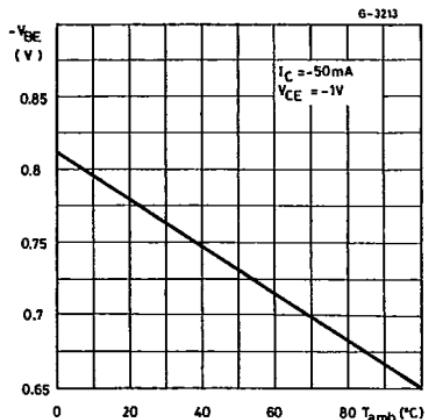
Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-base Voltage ( $I_E = 0$ )	- 40	V
$V_{CEO}$	Collector-emitter Voltage ( $I_B = 0$ )	- 40	V
$V_{EBO}$	Emitter-base Voltage ( $I_C = 0$ )	- 5	V
$I_C$	Collector Current	- 0.5	A
$P_{tot}$	Total Power Dissipation at $T_{amb} \leq 25^\circ C$ at $T_{case} \leq 25^\circ C$	0.7 3	W W
$T_{stg}$	Storage Temperature	- 55 to 200	°C
$T_J$	Junction Temperature	200	°C

$R_{th\ j\ -case}$	Thermal Resistance Junction-case	Max	58	°C/W
$R_{th\ j\ -amb}$	Thermal Resistance Junction-ambient	Max	250	°C/W

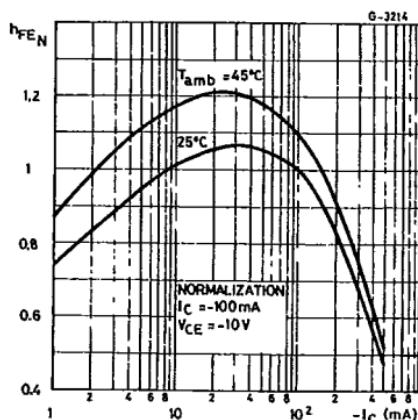
**ELECTRICAL CHARACTERISTICS ( $T_{amb} = 25^\circ C$  unless otherwise specified)**

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{CBO}$	Collector Cutoff Current ( $I_E = 0$ )	$V_{CB} = -30\text{ V}$ $V_{CB} = -30\text{ V}$ $T_{amb} = 75^\circ C$			-100 -50	nA µA
$V_{(BR)CBO}$	Collector-base Breakdown Voltage ( $I_E = 0$ )	$I_C = -10\text{ }\mu\text{A}$	-40			V
$V_{(BR)CEO}^*$	Collector-emitter Breakdown Voltage ( $I_B = 0$ )	$I_C = -10\text{ mA}$	-40			V
$V_{(BR)EBO}$	Emitter-base Breakdown Voltage ( $I_C = 0$ )	$I_E = -10\text{ }\mu\text{A}$	-5			V
$V_{CE(sat)}^*$	Collector-emitter Saturation Voltage	$I_C = -300\text{ mA}$ $I_B = -30\text{ mA}$ $I_C = -500\text{ mA}$ $I_B = -50\text{ mA}$		-0.45 -1	-0.8	V
$V_{BE}^*$	Base-emitter Voltage	$I_C = -10\text{ mA}$ $V_{CE} = -10\text{ V}$ $I_C = -100\text{ mA}$ $V_{CE} = -10\text{ V}$ $I_C = -300\text{ mA}$ $V_{CE} = -1\text{ V}$		-0.7		V
			-0.77		V	
			-0.97		V	
$h_{FE}^*$	DC Current Gain	$I_C = -10\text{ mA}$ $V_{CE} = -10\text{ V}$ $I_C = -100\text{ mA}$ $V_{CE} = -10\text{ V}$ $I_C = -150\text{ mA}$ $V_{CE} = -1\text{ V}$ $I_C = -300\text{ mA}$ $V_{CE} = -1\text{ V}$	40	90		
				90		
$f_T$	Transition Frequency	$I_C = -50\text{ mA}$ $V_{CE} = -10\text{ V}$	20	45		
				200		MHz
$C_{CBO}$	Collector-base Capacitance	$I_E = 0$ $f = 1\text{ MHz}$	$V_{CB} = -10\text{ V}$		6	pF

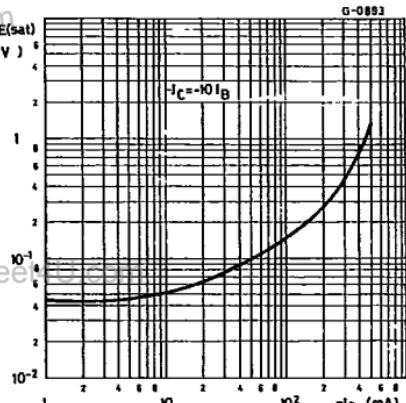
\* Pulsed : pulse duration = 300 µs, duty cycle = 1 %.



## DC Normalized Current Gain.



## Collector-emitter Saturation Voltage.



## Power Rating Chart.

